



ELECTRONICS, INC.  
 44 FARRAND STREET  
 BLOOMFIELD, NJ 07003  
 (973) 748-5089  
<http://www.nteinc.com>

## NTE2367 (NPN) & NTE2368 (PNP) Silicon Complementary Transistors Digital <sup>w/2</sup> Built-In 4.7k Bias Resistors

**Features:**

- Built-In Bias Resistor ( $R_1 = 4.7k\Omega$ ,  $R_2 = 4.7k\Omega$ )
- Small-Sized Package (TO92 type)

**Applications:**

- Switching Circuit
- Inverter
- Interface Circuit
- Driver

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Collector to Base Voltage, $V_{CBO}$ .....	50V
Collector to Emitter Voltage, $V_{CEO}$ .....	50V
Emitter to Base Voltage, $V_{EBO}$ .....	10V
Collector Current, $I_C$	
Continuous .....	100mA
Peak .....	200mA
Collector Dissipation, $P_C$	
NTE2367 .....	300mW
NTE2368 .....	200mW
Operating Junction Temperature, $T_J$ .....	+150°C
Storage Temperature Range, $T_{stg}$ .....	-55° to +160°C

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 40V, I_E = 0$	-	-	0.1	$\mu\text{A}$	
	$I_{CEO}$	$V_{CE} = 40V, I_B = 0$	-	-	0.5	$\mu\text{A}$	
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 5V, I_C = 0$	170	250	330	$\mu\text{A}$	
DC Current Gain	$h_{FE}$	$V_{CE} = 5V, I_C = 10\text{mA}$	30	-	-		
Current Gain-Bandwidth Product	$f_T$	$V_{CE} = 10V, I_C = 5\text{mA}$	NTE2367	-	250	-	MHz
			NTE2368	-	200	-	MHz
Output Capacitance	$C_{ob}$	$V_{CB} = 10V, f = 1\text{MHz}$	-	3.0	-	pF	

**Electrical Characteristics (Cont'd):** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 5\text{mA}, I_B = 0.25\text{mA}$	-	0.1	0.3	V
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\mu\text{A}, I_E = 0$	50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 100\mu\text{A}, R_{BE} = \infty$	50	-	-	V
Input OFF Voltage	$V_{I(off)}$	$V_{CE} = 5\text{V}, I_C = 100\mu\text{A}$	1.0	-	1.5	V
Input ON Voltage	$V_{I(on)}$	$V_{CE} = 200\text{mV}, I_C = 5\text{mA}$	1.1	-	2.0	V
Input Resistance	$R_1$		3.29	4.7	6.11	$k\Omega$
Input Resistance Ratio	$R_1/R_2$		0.9	1.0	1.1	

**Schematic Diagram**

